NSN 5962-01-575-2422

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View Online at https://aerobasegroup.com/nsn/5962-01-575-
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Features Provided:
Burn in and programmable and monolithic and w/clock
Inclosure Material:
Silicon
Inclosure Configuration:
Pin grid array
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Case Outline Source And Designator:
Cmga8-+156 joint electron device engineering council
Product Name:
5000 gate programmable array
Voltage Rating And Type Per Characteristic:
-0.5 volts power source and 7.0 volts power source
Time Rating Per Chacteristic:
4.00 nanoseconds output and 4.00 nanoseconds access
Memory Device Type:
Ram
Special Features:
Burn in iaw mil-std-883, class q
Precious Material And Location:
Terminal leads gold
Precious Material:
Gold
Terminal Type And Quantity:
156 pin
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli

Fiig:

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